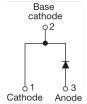


HEXFRED®, Ultrafast Soft Recovery Diode, 15 A





PRIMARY CHARACTERISTICS							
I _{F(AV)}	15 A						
V _R	600 V						
V _F at I _F	1.2 V						
t _{rr} typ.	23 ns						
T _J max.	150 °C						
Circuit configuration	Single						
Package	2L TO-220AC						

FEATURES

- · Ultrafast and ultrasoft recovery
- Very low I_{RRM} and Q_{rr}
- Designed and qualified according to JEDEC®-JESD 47





BENEFITS

- · Reduced RFI and EMI
- · Reduced power loss in diode and switching transistor
- Higher frequency operation
- Reduced snubbing
- · Reduced parts count

DESCRIPTION

VS-HFA15TB60... is a state of the art ultrafast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 600 V and 15 A continuous current, the VS-HFA15TB60... is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultrafast recovery time, the HEXFRED® product line features extremely low values of peak recovery current (IRRM) and does not exhibit any tendency to "snap-off" during the tb portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED VS-HFA15TB60... is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS					
Cathode to anode voltage	V _R		600	V					
Maximum continuous forward current	I _F	T _C = 100 °C	15						
Single pulse forward current	I _{FSM}		150	Α					
Maximum repetitive forward current	I _{FRM}		60						
Maximum power dissipation	В	T _C = 25 °C	74	w					
iviaximum power dissipation	P _D	T _C = 100 °C	29	, vv					
Operating junction and storage temperature range	T _J , T _{Stg}		-55 to +150	°C					



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ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS		
Cathode to anode breakdown voltage	V _{BR}	Ι _R = 100 μΑ	600	-	-				
Maximum forward voltage	V _{FM}	I _F = 15 A		-	1.3	1.7	V		
		I _F = 30 A	See fig. 1	-	1.5	2.0			
		I _F = 15 A, T _J = 125 °C		-	1.2	1.6			
Maximum reverse		$V_R = V_R$ rated	See fig. 2	-	1.0	10	μА		
leakage current	I _{RM}	$T_J = 125$ °C, $V_R = 0.8 \times V_R$ rated	See lig. 2	-	400	1000			
Junction capacitance	C _T	V _R = 200 V See fig. 3		-	25	50	pF		
Series inductance	L _S	Measured lead to lead 5 mm from p	ackage body	-	8.0	-	nH		

DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS		
	t _{rr}	$I_F = 1.0 \text{ A}, di_F/dt = 200 \text{ A}$	A/μs, V _R = 30 V	-	19	-	ns		
Reverse recovery time See fig. 5	t _{rr1}	T _J = 25 °C		-	42	60			
oco ng. o	t _{rr2}	T _J = 125 °C		-	74	120			
Peak recovery current	I _{RRM1}	T _J = 25 °C		-	4.0	6.0	- A - nC		
See fig. 6	I _{RRM2}	T _J = 125 °C	I _F = 15 A	-	6.5	10			
Reverse recovery charge	Q _{rr1}	$T_J = 25 ^{\circ}C$	di _F /dt = 200 A/μs - V _B = 200 V	-	84	180			
See fig. 7	Q _{rr2}	T _J = 125 °C	VR - 200 V	-	241	600			
Peak rate of fall of recovery	di _{(rec)M} /dt1	T _J = 25 °C		-	188	-	A/μs		
current during t _b See fig. 8	di _{(rec)M} /dt2	T _J = 125 °C		-	160	-			

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS			
Lead temperature	T _{lead}	0.063" from case (1.6 mm) for 10 s	-	-	300	°C			
Thermal resistance, junction to case	R _{thJC}		-	-	1.7	K/W			
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	-	80				
Weight			-	2.0	-	g			
vveignt			-	0.07	-	oz.			
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)			
Marking device		Case style 2L TO-220AC		HFA1	5TB60				

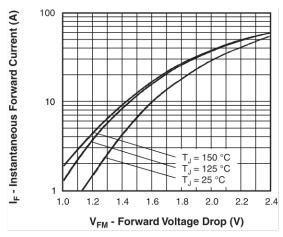


Fig. 1 - Maximum Forward Voltage Drop vs. Instantaneous Forward Current

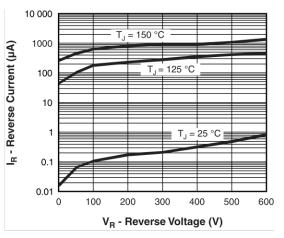


Fig. 2 - Typical Reverse Current vs. Reverse Voltage

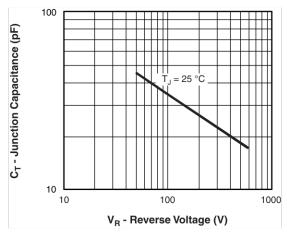


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

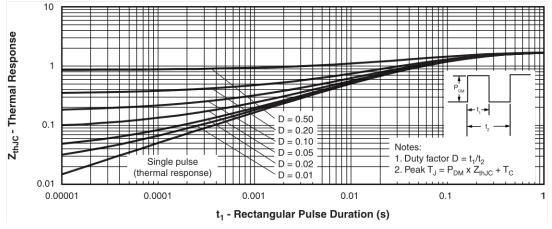


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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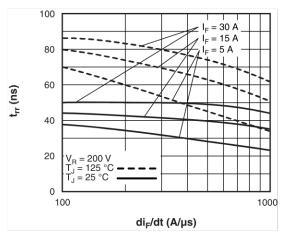


Fig. 5 - Typical Reverse Recovery Time vs. di_F/dt

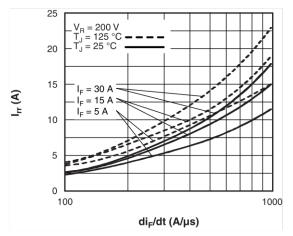


Fig. 6 - Typical Recovery Current vs. di_F/dt

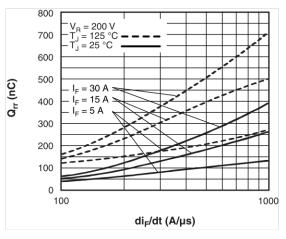


Fig. 7 - Typical Stored Charge vs. di_F/dt

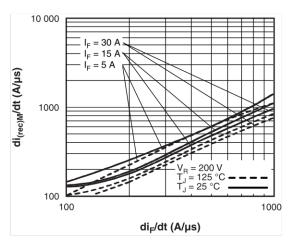


Fig. 8 - Typical di_{(rec)M}/dt vs. di_F/dt

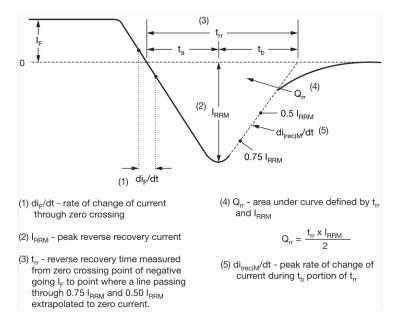
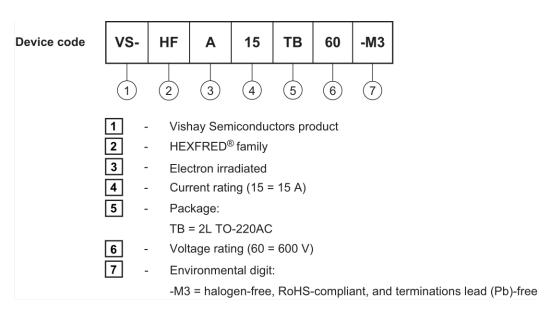


Fig. 9 - Reverse Recovery Waveform and Definitions



ORDERING INFORMATION TABLE



ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-HFA15TB60-M3	50	1000	Antistatic plastic tube					

LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?96156					
Part marking information	www.vishay.com/doc?95391					



INCHES

MAX. 0.507

0.414

0.350

0.105

0.208

0.255

0.552 0.150

0.154

0.118

NOTES

6

3, 6

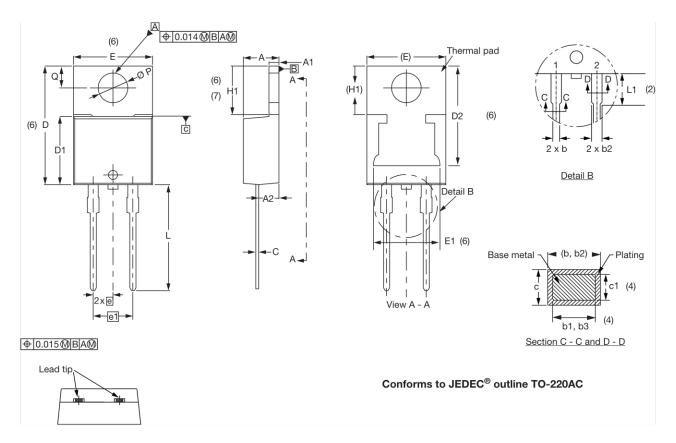
6

6, 7

2

2L TO-220AC

DIMENSIONS in millimeters and inches



SYMBOL	MILLIN	IETERS	INCHES		NOTES		SYMBOL	MILLIN	IETERS	IN
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES		STMBOL	MIN.	MAX.	MIN.
Α	4.25	4.65	0.167	0.183]	D2	11.68	12.88	0.460
A1	1.14	1.40	0.045	0.055]	E	10.11	10.51	0.398
A2	2.50	2.92	0.098	0.115]	E1	6.86	8.89	0.270
b	0.69	1.01	0.027	0.040			е	2.41	2.67	0.095
b1	0.38	0.97	0.015	0.038	4]	e1	4.88	5.28	0.192
b2	1.20	1.73	0.047	0.068]	H1	6.09	6.48	0.240
b3	1.14	1.73	0.045	0.068	4]	L	13.52	14.02	0.532
С	0.36	0.61	0.014	0.024]	L1	3.32	3.82	0.131
c1	0.36	0.56	0.014	0.022	4]	ØР	3.54	3.91	0.139
D	14.85	15.35	0.585	0.604	3]	Q	2.60	3.00	0.102
D1	8.38	9.02	0.330	0.355]				

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3, and c1 apply to base metal only
- Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2, and E1
- (7) Outline conforms to JEDEC® TO-220, except D2 (minimum)



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